

FORM PTO-1449 (SUBSTITUTE)

U.S. DEPARTMENT OF COMMERCE
PATENT AND TRADEMARK OFFICEAttorney Docket No.:
1999P8006 PApplic. No.
09/915,985

Applicant

Detlef Hommel et al.

Filing Date
July 25, 2001Group Art Unit
2811INFORMATION DISCLOSURE
STATEMENT BY APPLICANT
(37 CFR 1.98(b))

U.S. PATENT DOCUMENTS

EXAMINER INITIALS		PATENT NO.	DATE	PATENTEE	CLASS	SUB CLASS	FILING DATE
/	A						
/	B						
/	C						
/	D						
/	E						
/	F						
/	G						
/	H						
/	I						

FOREIGN PATENT DOCUMENT

		DOCUMENT NO.	DATE	COUNTRY	CLASS	SUB CLASS	TRANSL. YES NO
Jm2	J	WO 97/23912	07/03/97	WIPO			X
/	K						
/	L						
/	M						
/	N						

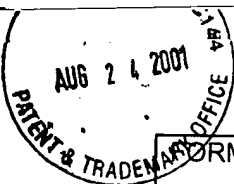
OTHER DOCUMENTS (Including Author, Title, Date, Pertinent Pages, etc.)

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EXAMINER

DATE CONSIDERED

EXAMINER: Initial if citation considered, whether or not citation is in conformance with MPEP 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.



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EXAMINER INITIALS		PATENT NO.	DATE	PATENTEE	CLASS	SUB CLASS	FILING DATE
JH2	A	4,570,172	02/86	Henry et al.			
JH2	B	4,775,876	10/88	Moyer			
	C						
	D						
	E						
	F						
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		DOCUMENT NO.	DATE	COUNTRY	CLASS	SUB CLASS	TRANSL. YES NO
JH2	J	PCT/SE92/00210	11/92	WIPO			X
JH2	K	PCT/DE97/01337	12/97	WIPO			X
JH2	L	EP 0 977 278 A2	02/00	Europe			X
JH2	M	0 486 052 A1	05/92	Europe			X
JH2	N	0 114 548	08/84	Europe			X

OTHER DOCUMENTS (Including Author, Title, Date, Pertinent Pages, etc.)

JH2	O	Yu et al.: "Blue-green laser diodes on ZnSe substrates", Electronics Letters, August 3, 1995, Vol. 31, No. 16, pages 1341 - 1342
JH2	P	Gumlich: "Some Aspects of Impurities in Wide-Band Gap II-VI Compounds", Growth and Optical Properties of Wide-Gap II-VI Low-Dimensional Semiconductors, Plenum Press, New York and London, NATO ASI Series B: Physics Vol. 200, 1989, pages 109-118

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		DOCUMENT NO.	DATE	COUNTRY	CLASS	SUB CLASS	TRANSL. YES NO
1m2	J	EP 0 971 421 A2	01/00	Europe			X
↓	K	10056203	08/96	Japan			X
	L	10261818	03/97	Japan			X
	M	11274558	03/98	Japan			X
	N						

OTHER DOCUMENTS (Including Author, Title, Date, Pertinent Pages, etc.)

2m2	O	Kukimoto: "Conductivity Control of Wide Gap II-VI Compounds", NATO ASI Series B, Physics Vol. 200, Plenum Press, New York, 1998, pages 119 - 127.
	P	

EXAMINER <i>[Signature]</i>	DATE CONSIDERED <i>Jan 10, 2003</i>
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